## NSN 5961-01-132-9135

**Fiig:** A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-132-9135 **Inclosure Material:** Plastic **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Height:** Between 0.125 inches and 0.165 inches **Overall Width:** Between 0.175 inches and 0.205 inches **End Application:** 21793-9009n 21793 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 45.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current and 200.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No